

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	423	getter\$6 same (sin "si.sub.3n.sub.4" "si.sub.3 n.sub.4" nitride) same ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:34
L2	146	(getter\$6 with (sin "si.sub.3n.sub.4" "si.sub.3 n.sub.4" nitride)) same ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:33
L3	127	(getter\$6 with (sin "si.sub.3n.sub.4" "si.sub.3 n.sub.4" nitride)) same ((silicon si semiconductor epitax\$8 amorphous) near2 (film layer))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:33
L4	29	2 same (tft gate source drain)	US-PGPUB; USPAT	OR	ON	2006/05/03 13:11
L5	133	getter\$6 and (sin "si.sub.3n.sub.4" "si.sub.3 n.sub.4" nitride) and ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 11:34
L6	112	1 same (tft gate source drain)	US-PGPUB; USPAT	OR	ON	2006/05/03 11:36
L7	27	5 and (tft gate source drain)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 14:20
L8	2164	438/151.ccls. 438/476.ccls. 438/791.ccls.	US-PGPUB; USPAT	OR	OFF	2006/05/03 11:37
L9	119	L8 and (getter\$6 same ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer)) same (tft gate source drain))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:37
L10	74	L8 and (getter\$6 same (sin "si.sub.3n.sub.4" "si.sub.3 n.sub.4" nitride))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:40
L14	2	1997jp-0205345.ap,prai.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/05/03 15:40
L15	2	jp-11031824-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/05/03 15:41
S3	2160	438/151.ccls. 438/476.ccls. 438/791.ccls.	US-PGPUB; USPAT	OR	OFF	2006/05/01 15:52

## EAST Search History

S4	317	438/476.ccls.	US-PGPUB; USPAT	OR	OFF	2006/05/01 15:53
S5	50	("5059556" "5492843" "5501989"  "5529937" "5569610" "5569936"  "5580792" "5595923" "5595944"  "5605846" "5606179" "5612250"  "5621224" "5637515" "5639698"  "5646424" "5654203" "5663077"  "5670411" "5677549" "5700333"  "5734195" "5744822" "5744824"  "5773327" "5773846" "5783468"  "5837619" "5874348" "5879977"  "5882960" "5897347" "5904770"  "5923962" "5929464" "5942768"  "5956579" "5961743" "5966594"  "5985704" "6060725" "6071764"  "6074901" "6077758" "6090646"  "6133075" "6140165" "6140213"  "6444390" "6693044").PN.	US-PGPUB; USPAT	OR	OFF	2006/05/02 15:25
S6	12	jp-06338507-\$.did. jp-07201842-\$.did. jp-08078329-\$.did. jp-09312260-\$.did. jp-10247735-\$.did. jp-10270363-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/05/02 16:52
S7	2164	438/151.ccls. 438/476.ccls. 438/791.ccls.	US-PGPUB; USPAT	OR	OFF	2006/05/02 16:52
S8	350	S7 and getter\$6	US-PGPUB; USPAT	OR	ON	2006/05/02 16:53
S10	281	S7 and (getter\$6 same ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer)))	US-PGPUB; USPAT	OR	ON	2006/05/03 11:37
S11	231	S7 and (getter\$6 with ((silicon si semiconductor epitax\$8 thin amorphous) near2 (film layer)))	US-PGPUB; USPAT	OR	ON	2006/05/02 16:59